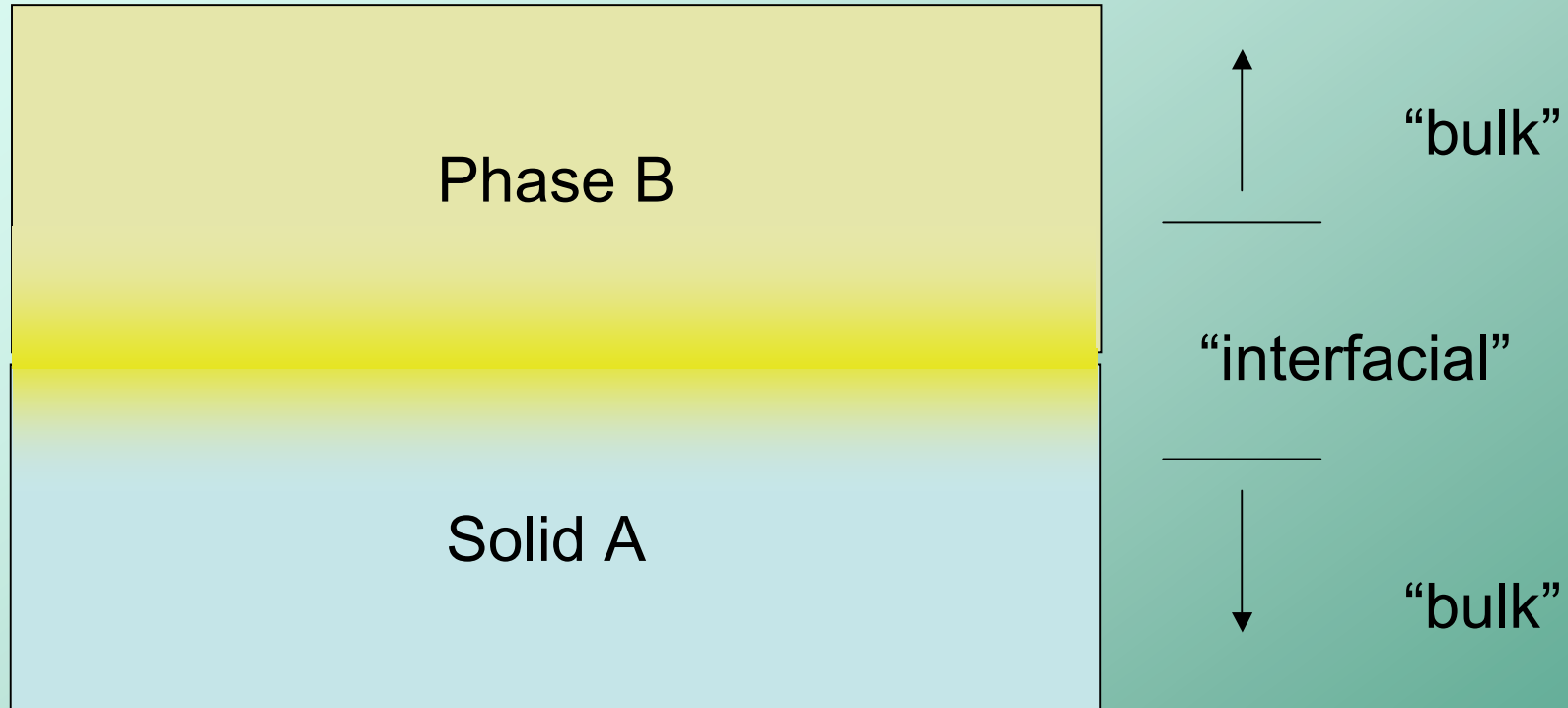
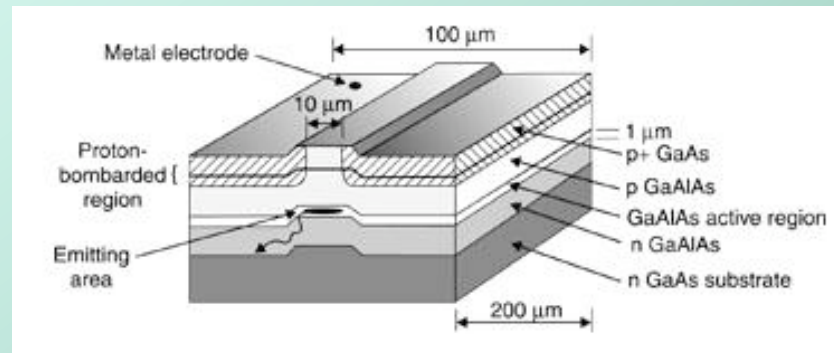


Solid surfaces



In the applications of chemistry we are frequently concerned with how a solid phase interacts with its environment

Solid -Solid



- *Adhesion and coatings*
- *Functional solid state devices*
- *Nanotechnology*

Solid liquid

- Electrochemistry
- Detergent action

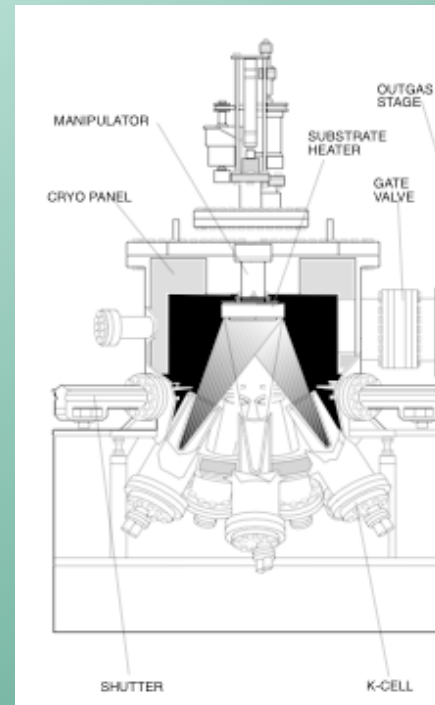


Solid gas

- Catalysis



- Thin films



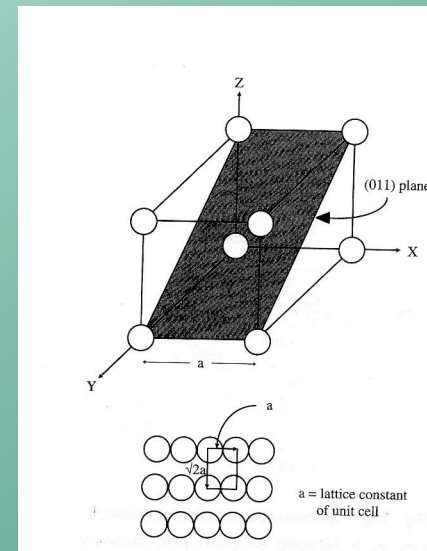
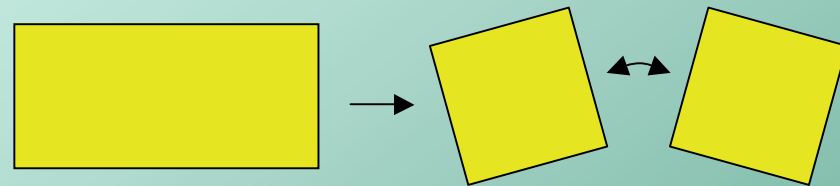
In this introduction we will focus on the chemistry of the gas-solid interface

Books

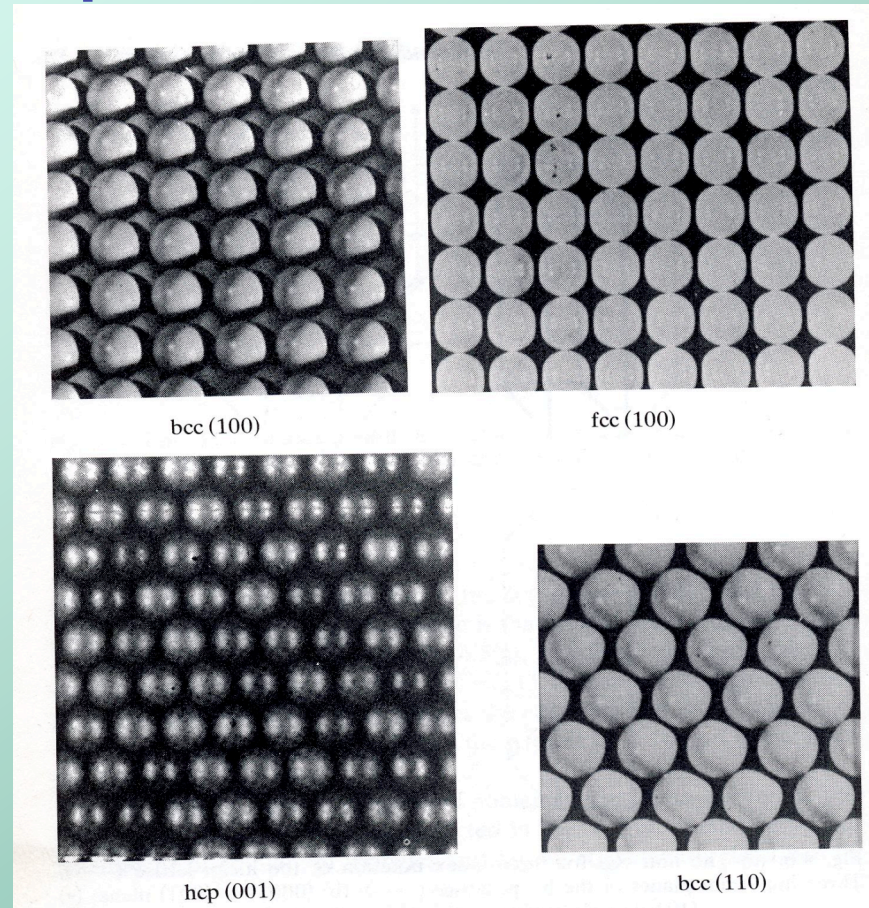
- Atkins “Physical Chemistry”
- Attard “Surfaces” (Oxford chemistry primer)
- Bowker “Heterogeneous catalysis” (Oxford chemistry primer)
- Gasser “An Introduction to Chemisorption and Catalysis by Metals” (College libraries etc)

Atomic structure at solid surfaces

- Consider preparation of a surface by cleavage of a bulk **single crystal**
- Atomic structure will depend on how the surface is oriented w.r.t. the unit cell



Surface lies parallel to a dense atomic plane in the bulk crystal



- Expect to see atomically ordered smooth surfaces

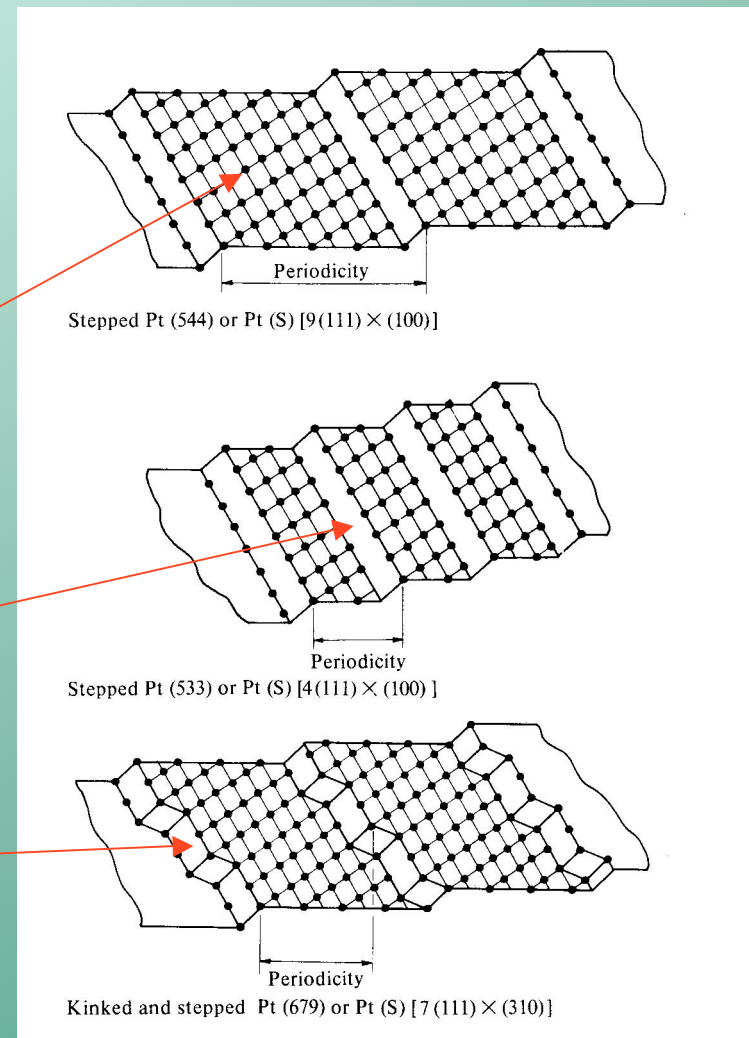
Surface is tilted w.r.t. to dense crystal planes

- Atomically rough
- TSK model - terrace-step-kink

Terrace

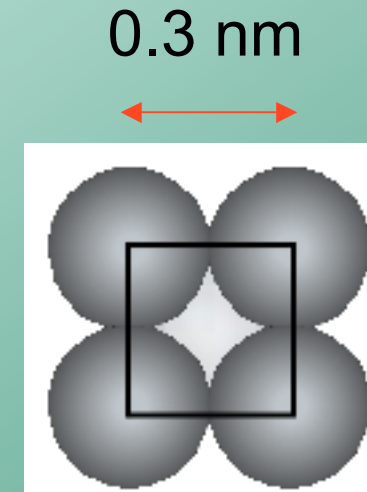
Step

Kink



Atomic concentration

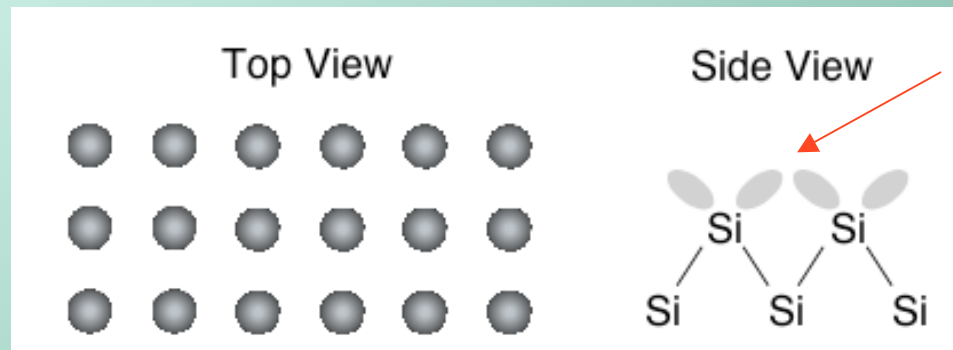
- Area of unit cell $= (0.3 \times 10^{-9})^2 \text{ m}^2$
- 1 atom per unit cell
- Therefore $1 / (0.3 \times 10^{-9})^2$
 $= 1.1 \times 10^{19} \text{ atoms m}^{-2}$
 $= 1.1 \times 10^{15} \text{ atoms cm}^{-2}$



Order of magnitude correct for most surfaces

Chemical reactivity of surfaces

- Clean surfaces are often highly reactive - "unsatisfied valence"



Dangling bonds

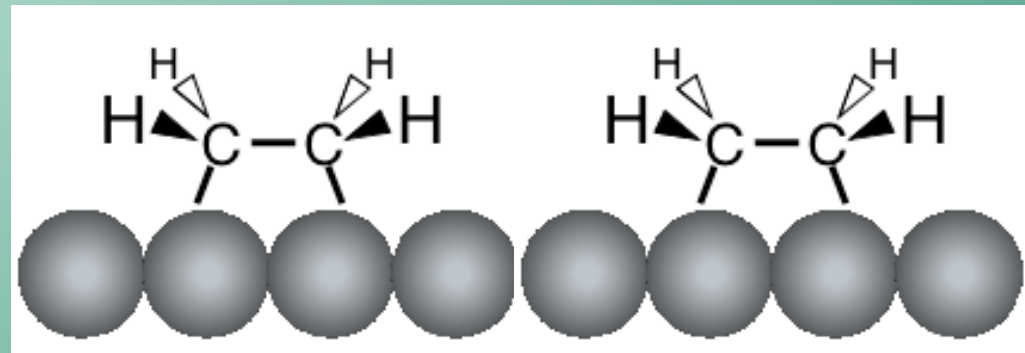
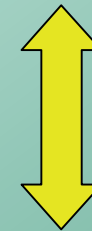
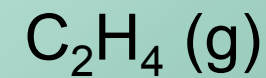
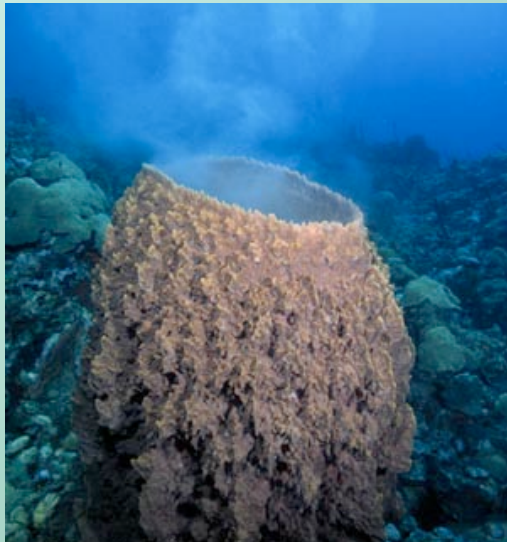
Surface - 2 coord.

Bulk - 4 coord

- Therefore expect to react with ambient gaseous species

Adsorption

- Gaseous molecule becomes trapped at the surface and forms a bond to it.
- Don't confuse it with absorption!



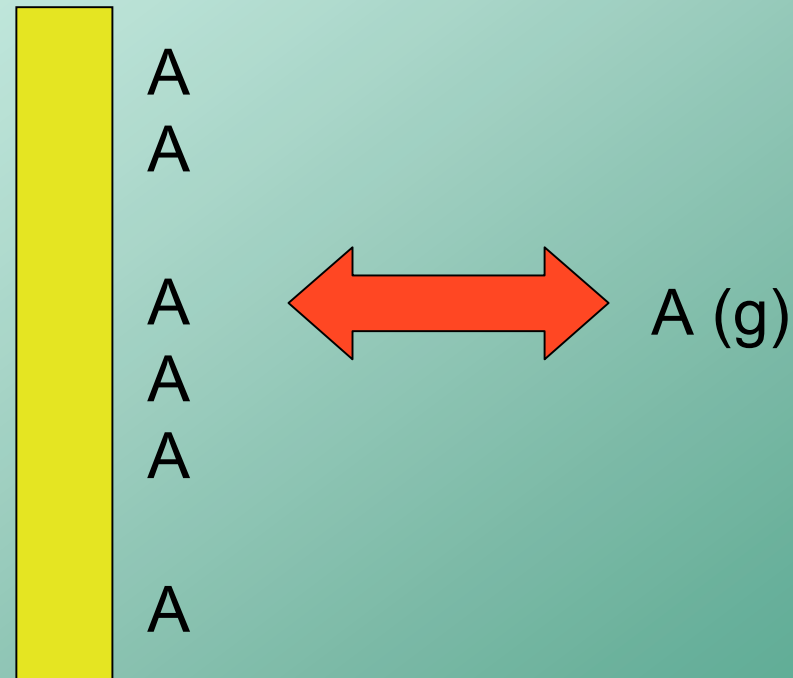
Silver Surface

Thermodynamics

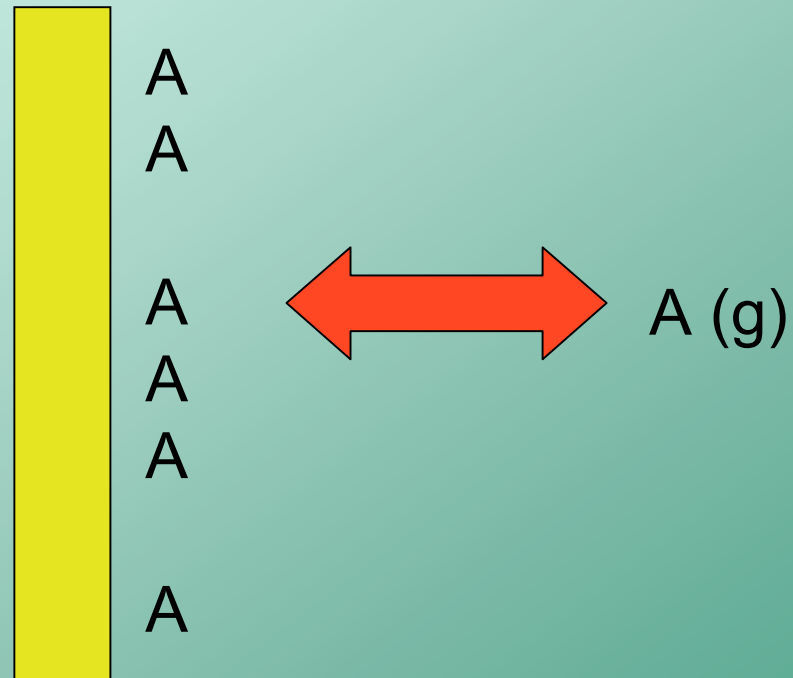
- ΔS_{ads} = entropy of (adsorbed phase - gas phase)
- ΔH_{ads} = enthalpy of (adsorbed phase-gas phase)
- ΔS_{ads} is negative (loss of disorder)
- However so is ΔH_{ads} (exothermic process)
- So occurs spontaneously (exoergic process driven by the enthalpy of bond formation)

Adsorption Isotherms

- Consider equilibrium between adsorbed and gas phase
- Extent of adsorption will increase as i. P_A rises; ii. T falls (Le Chatelier etc.)



- θ_A = fraction of surface occupied with adsorbed A.
- Then expect $\theta_A = f(P_A, T)$
- At a constant temperature $\theta_A = f(P_A)$
- *This relationship is known as the **adsorption isotherm***



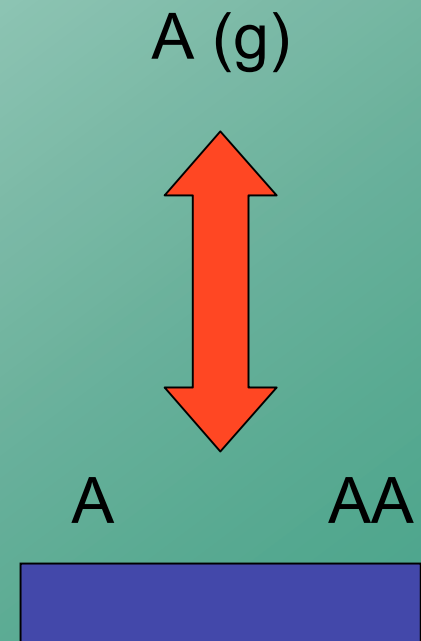
Langmuir adsorption isotherm

- Recap 2nd yr

adsorption rate \propto *pressure* \times *conc. of bare surface*
 $= k^{ads} (1 - \theta_A) p_A$

desorption rate \propto *conc. of adsorbate*
 $= k^{des} \theta_A$

$$\theta_A = \frac{B p_A}{1 + B p_A} \quad \text{where} \quad B = \frac{k^{ads}}{k^{des}}$$

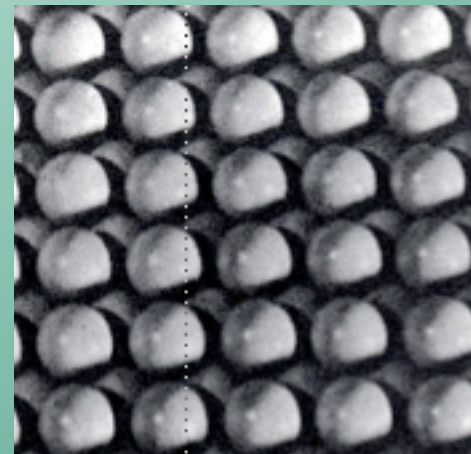
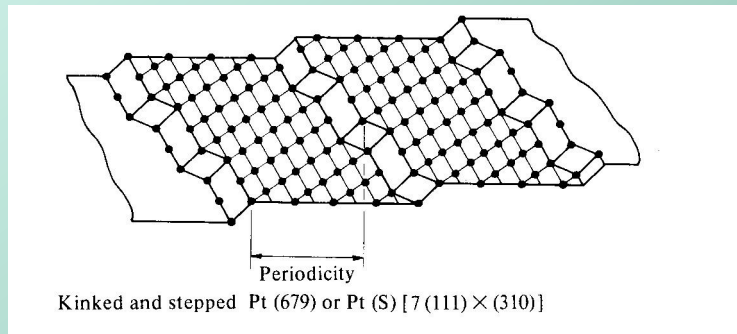


But.....

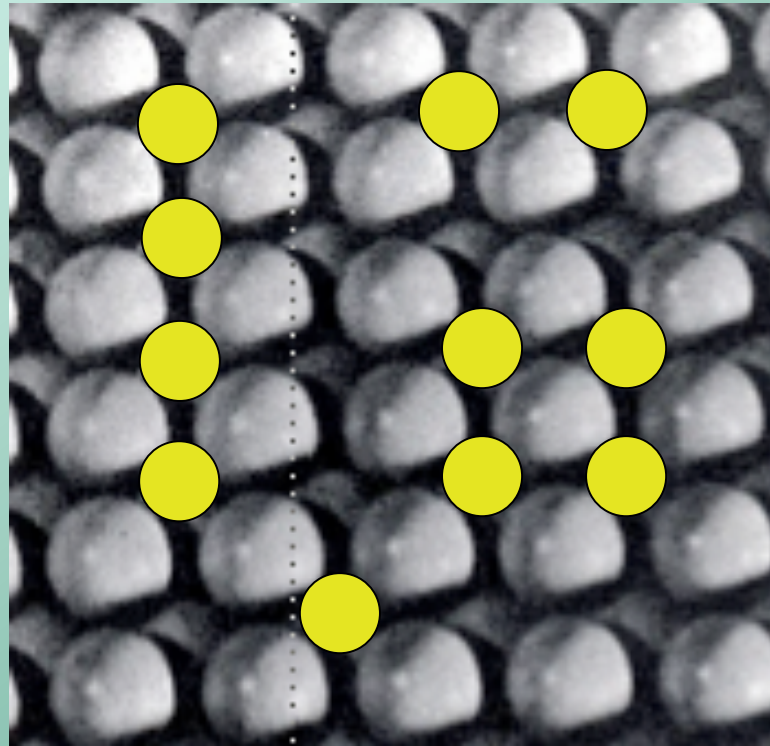
- Isotherm is an equilibrium property - normally understood by considering state of reactants and products.
- Above derivation doesn't identify what adsorbed phases it might apply to (all?)
- Experimental measurement of the kinetics of adsorption/desorption shows the assumptions above seldom apply!

Langmuir isotherm using a statistical mechanics approach

- Surface is a uniform array of adsorption sites

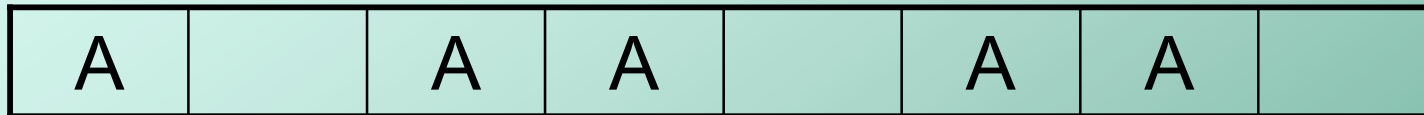


- Adsorbed phase consists of species localised in a fraction θ of the available sites.
- No interaction between species on adjacent sites (i.e. random occupancy)



The configurational entropy of the adsorbed phase

- A normal “distinguishable system” with some extra **configurational** entropy.



- M sites (boxes), N molecules. $\theta = N/M$

$$S^{config} = k \ln W^{config} = k \ln \left(\frac{M \cdot (M-1)(M-2) \dots}{N!} \right)$$
$$= k \ln \left(\frac{M!}{(M-N)! N!} \right)$$

The Helmholtz energy of the adsorbed phase

$$A^{normal} = U - TS = N\varepsilon_o - NkT \ln q$$

$$A^{ads} = N\varepsilon_o - NkT \ln q - TS^{config}$$

$$= N\varepsilon_o - NkT \ln q - kT \ln \left(\frac{M!}{(M-N)!N!} \right)$$

Equation 1



Use of Stirling approx. ($\ln x! = x \ln x - x$) (optional)

$$\ln \left(\frac{M!}{(M-N)!N!} \right) \quad \text{Equation 2}$$

$$= k \left[M \ln M - N \ln N - (M-N) \ln(M-N) \right]$$

- Inserting (2) into (1) yields A for the adsorbed phase, and differentiating with respect to N yields the chemical potential of this phase since from stat mech

$$\mu = \left(\frac{\partial A}{\partial N} \right)_T$$

The result for the chemical potential (optional)

$$\mu^{ads} = \varepsilon_o^{ads} - kT \ln q^{ads} - kT \ln \left(\frac{\binom{M-N}{N}}{N} \right)$$

$$= \varepsilon_o^{ads} - kT \ln \left[q^{ads} \left(\frac{1}{\theta} - 1 \right) \right]$$

$$\mu^{gas} = \varepsilon_o^{gas} - kT \ln \left[\frac{\left(\frac{q_{gas}}{V} \right) kT}{P_{gas}} \right]$$

The isotherm!

- At equilibrium $\mu^{\text{gas}} = \mu^{\text{ads}}$ which yields after rearrangement

$$\theta_A = \frac{Bp_A}{1 + Bp_A}$$

“Langmuir isotherm”

$$B = \frac{1}{kT} \left(\frac{q^{\text{ads}}}{\left(\frac{q^{\text{gas}}}{V} \right)} \right) \exp \left(\frac{\epsilon_o^{\text{gas}} - \epsilon_o^{\text{ads}}}{kT} \right)$$